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Inhomogeneous broadening and trap effect in hole burning of Sm^{2+} -doped mixed crystals

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We report the results of the inhomogeneous broadening and high temperature hole burning in $M_1M'_{1-y}FClo_sBr_{0.5}Br_{0.5}:Sm^{2+}$ system ($M, M' = \text{Ca, Sr, Ba}; y = 0-1$). The influence of Sm^{3+} as electron trap on hole burning is discussed and new trap is introduced in Yb-doped $\text{SrFCI}_x\text{Sm}^{2+}$ crystals.

1. Introduction

In recent years, much research work has been performed on spectral hole burning. One of the important reasons is that hole burning has a potential use in frequency domain optical storage. In practice, high temperature photon gated persistent hole burning is required. One of the factors limiting the hole burning temperature is the ratio of the inhomogeneous line width to the hole width. The ratio decreases rapidly with increasing temperature because of the unchanged inhomogeneous line width and the exponentially increased hole width with increasing temperature, so hole burning is impossible as the hole width is equivalent to the inhomogeneous line width at a temperature. Obviously, to broaden the inhomogeneous line is necessary to raising hole burning temperature. In 1985, Winnacker et al. [1] first reported photon gated persistent hole burning in $\text{BaFCl}:\text{Sm}^{2+}$ at 2 K. However, high temperature hole burning cannot be performed in this material because of the narrow inhomogeneous line of Sm^{2+} . In this case, we started to experiment on inhomogeneous broadening and successfully prepared a high temperature hole burning system $\text{BaFCl}_x\text{Br}_{1-x}:\text{Sm}^{2+}$ [2,3], in which the inhomogeneous line is broadened greatly

and the line width approaches a maximum with $x = 0.5$. Liquid nitrogen temperature hole burning was observed for the first time in $\text{BaFCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ in our laboratory [2]. Since then, the investigations on high temperature hole burning in $\text{BaFCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ have been undertaken [4,5] and room temperature hole burning was realized in $\text{SrFClo}_s\text{Br}_{0.5}:\text{Sm}^{2+}$ crystals by Jaaniso et al. [6]. Considering the useful properties of $\text{MFClo}_s\text{Br}_{0.5}:\text{Sm}^{2+}$ systems ($M = \text{group II ion}$), our interest is to understand if the inhomogeneous line can be broadened further when Br and the other alkaline earth metals are simultaneously doped to $\text{BaFCl}:\text{Sm}^{2+}$ matrix. Therefore we prepared the $M_1M'_{1-y}FClo_sBr_{0.5}Br_{0.5}:\text{Sm}^{2+}$ series ($M, M' = \text{Sr, Ba}; y = 0-1$). Fortunately the inhomogeneous line in the series is indeed broadened further and room temperature hole burning was observed by Holliday et al. in $\text{Sr}_{0.5}\text{Mg}_{0.5}\text{FClo}_s\text{Br}_{0.5}:\text{Sm}^{2+}$ prepared in our laboratory [7]. In the paper we mainly report the results of inhomogeneous broadening and high temperature hole burning in the $\text{Ca}_y\text{Sr}_{1-y}$ and $\text{Sr}_y\text{Ba}_{1-y}$ series.

Although the Sm^{2+} -doped mixed crystals have some useful properties of high temperature photon gated hole burning [2-7] and high temperature stable hole [1,8], there is a problem to be solved. That is hole refilling in the hole burning process. The hole burning mechanism in this system is considered to be photoionization of Sm^{2+} following electron trapping, and Sm^{3+} ions usually act as

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of Sm^{2+} . The energy levels increases more than 20 cm^{-1} approaching 0.5 . To avoid the inhomogeneous width, we add $x = 0.5$ to form the $-y$ series. Their fluorescence at 77 K . The inhomogeneous energy (E_{J_0}) series are shown in the tables, we find the widths are beyond the rate of the variation that with x observed system, while the results are

substitutes the $\text{BaFCl}_x\text{Br}_{1-x}:\text{Sm}^{2+}$ ligands Cl^- and Br^- configurations with an increase of energy levels is the nearest substitution $= 0.5$ [3]. In the disordered is reposition of anions are located at

with E_{J_0} and energy level J_0

55	0.7	0.8
1466	38.5	39
14466	14458	14450
1		
24		
14483		
31		
15819		
20		
17760		

farther sites than anions to Sm^{2+} ions, so that the influence of combinations of different cations on the inhomogeneous line width is smaller than that of anions. The change of energy with y should be attributed to the variation of cation radius, which perturbs the crystal field. The change of energy with x in $\text{BaFCl}_x\text{Br}_{1-x}:\text{Sm}^{2+}$ is also found. We have observed that the energy changes linearly with x or y and follows the experimental relationships below:

$$E_{00} = 14550 - 24.7x \text{ (BaFCl}_x\text{Br}_{1-x}\text{)} \quad (1)$$

$$E_{00} = 14498 - 58.1y \text{ (Ca}_y\text{Sr}_{1-y}\text{)} \quad (2)$$

$$E_{00} = 14546 - 61.0y \text{ (Sr}_y\text{Ba}_{1-y}\text{)} \quad (3)$$

$$E_{10} = 15885 - 61.0y \text{ (Sr}_y\text{Ba}_{1-y}\text{)} \quad (4)$$

$$E_{20} = 17828 - 61.0y \text{ (Sr}_y\text{Ba}_{1-y}\text{)} \quad (5)$$

According to the above results, it is possible to mix the powder samples with different x or y together in proper proportion to form a mixture with a large inhomogeneous line width. In Eqs. (1)–(5), the energy changes faster with y than x and E_{J_0} changes with the same slope in $\text{Sr}_y\text{Ba}_{1-y}$ series. In view of this, three samples in the $\text{Sr}_y\text{Ba}_{1-y}$ series with $y = 0, 0.25$ and 0.65 are selected to mix together in a reasonable proportion. The inhomogeneous line shape in the mixture should be determined by the overlapping of the inhomogeneous lines of the three samples. To ${}^7\text{F}_0-{}^5\text{D}_2$ transition, an inhomogeneous line width of 62.5 cm^{-1} in the mixture is estimated by using the data of E_{20} and E_{10} in Table 2. Figs. 1(a) and (b) show

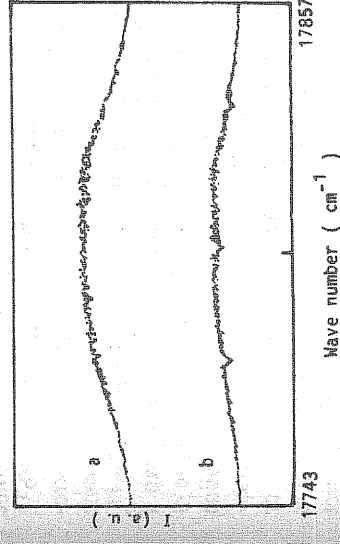


Fig. 1. The excitation spectra before (a) and after (b) burning three holes in the mixture of $\text{Sr}_y\text{Ba}_{1-y}$ series with different y of $0, 0.25$ and 0.65 at 77 K .

the excitation spectrum before and after burning three holes in the mixture at 77 K , respectively. The width of the spectral distribution is 65 cm^{-1} , which is in agreement with the estimation (62.5 cm^{-1}). In this way, a large inhomogeneous broadening can be realized while the homogeneous width is unchanged. In theory, room temperature hole burning in the mixture is possible. The experiment has not been done in the mixture; instead room temperature hole burning has been performed in the $\text{Sr}_y\text{Ba}_{1-y}$ series with $y = 0.5$.

Fig. 2 shows the normalized hole shape burn in the $\text{Sr}_y\text{Ba}_{1-y}$ series ($y = 0.5$) at room temperature. The burning time is 10 min . A hole with width of 7 cm^{-1} and depth of 15% is probed. At room temperature, ${}^5\text{D}_2-{}^7\text{F}_0$ emission has quenched and the non-radiative emission rate rises rapidly compared to that at 77 K ; then the homogeneous line width of ${}^5\text{D}_2-{}^7\text{F}_0$ emission increases faster than that of ${}^5\text{D}_1-{}^7\text{F}_0, {}^3\text{D}_0-{}^7\text{F}_0$ emissions with increasing temperature. It is reasonable to suppose that the hole burnt in ${}^7\text{F}_0-{}^5\text{D}_1$ or ${}^7\text{F}_0-{}^5\text{D}_0$ transition at room temperature is narrower than 7 cm^{-1} . The evidence for this is that the hole widths for ${}^7\text{F}_0-{}^5\text{D}_0$ and ${}^7\text{F}_0-{}^5\text{D}_1$ transitions in $\text{SrFCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ at room temperature are both less than 5 cm^{-1} [6], and the hole width for ${}^7\text{F}_0-{}^5\text{D}_1$ transition in $\text{Sr}_{0.5}\text{Mg}_{0.5}\text{FCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ is less than 7 cm^{-1} [7]. In view of these results, the $\text{M}_j\text{M}'_{1-y}$ series and their mixture are promising materials for room temperature hole burning, and the latter may have the advantage of multi-hole burning at room temperature.

3.2. Trap effect in hole burning

In Sm^{2+} -doped crystals, Sm^{3+} ions generally act as principal electron traps which leads to hole refilling in hole burning process and this effect has been observed in $\text{SrFCl}:\text{Sm}$ [9]. The evidence to verify that Sm^{3+} ions act as principal traps in $\text{SrFCl}:\text{Sm}$ is that the spectral area of Sm^{2+} remains constant before and after hole burning at 77 K [9]. The same result is also obtained at room temperature. Fig. 3 shows the spectral distributions of Sm^{2+} before (solid) and after (broken) line bleaching at room temperature in $\text{SrFCl}:\text{Sm}$. There are two

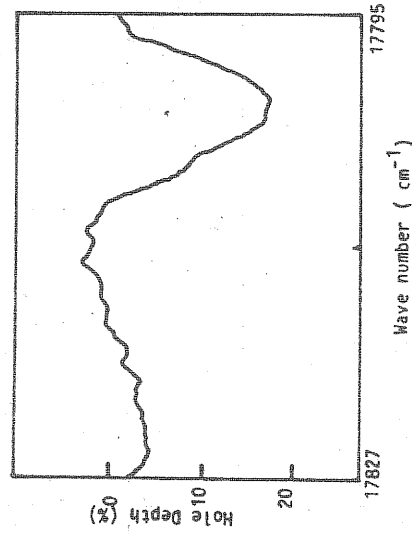


Fig. 2. Normalized hole shape burnt in the $\text{Sr}_y\text{Ba}_{1-y}$ series ($y = 0.5$) at room temperature.

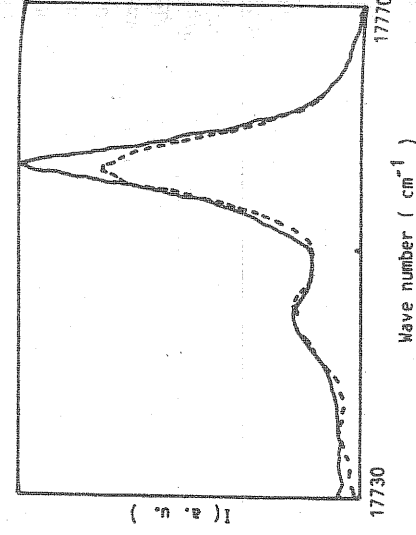


Fig. 4. The excitation spectra before (solid) and after (broken) bleaching the strong line in $\text{SrFCl}:\text{Sm}, \text{Yb}$ at room temperature.

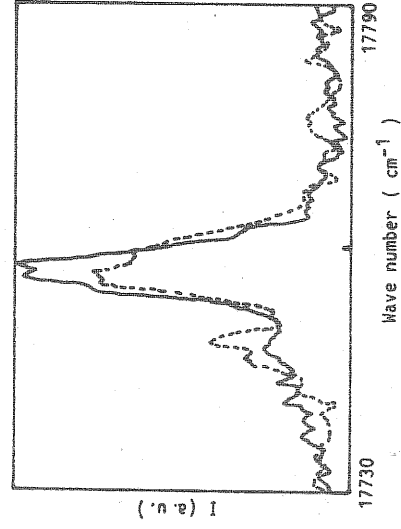


Fig. 3. The excitation spectra before (solid) and after (broken) bleaching the strong line in $\text{SrFCl}:\text{Sm}$ at room temperature.

lines in the ${}^7\text{F}_0-{}^5\text{D}_2$ transition profile, which stem from two different Sm^{2+} centers. After burning at the peak of the strong line, no hole is found because hole width for this transition at room temperature approaches the inhomogeneous line width; instead the intensity of the strong line decreases following the increase of intensity of the weak line. This feature is interpreted as that the free electrons released from the photoionization of Sm^{2+} responsible for the strong line are captured by Sm^{3+} ions at the weak line site to generate Sm^{2+} ions distributing under the weak line. The Sm^{2+} -ion transfer

4. Conclusion

High temperature $\text{M}_{1-y}\text{FCl}_{0.5}\text{Br}_0.5}$ prepared. In the Sm^{2+} is broader width of about 4 perature hole by $\text{FCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ homogeneous mixing three $y = 0, 0.25$ and burnt and probe temperature. To hole burning probe trap different Yb doubly doped

between the two different centers is essentially caused by the existence of the principal Sm^{3+} trap.

If the effective trap is different from Sm^{3+} , the spectral area should reduce. To introduce another trap, we dope Yb to $\text{SrFCl}:\text{Sm}^{2+}$. Fig. 4 shows the excitation spectra before (solid) and after (broken) bleaching the strong line in $\text{SrFCl}:\text{Sm}^{2+}$, $2\% \text{Yb}$ at room temperature. We see that the intensity of the strong line decreases and the intensity of the weak line keeps almost constant after bleaching the strong line. The result is because that almost no additional Sm^{2+} ions under the weak line are produced in the case of existence of new trap. The new trap in $\text{SrFCl}:\text{Sm}, \text{Yb}$ is not understood very well. They probably have some connection with the Yb ions. For instance, Yb^{3+} and some unknown color centers due to the introducing of Yb can act as effective traps. Some trivalent rare earth ions such as $\text{Eu}^{3+}, \text{Im}^{3+}, \text{Dy}^{3+}$ and Ho^{3+} , etc., can probably act as trap if they are doped to the hole burning system. One of the reasons for this is that these ions in alkaline earth fluoride can convert to divalent ions by trapping electrons generated by radiation of X- or γ -rays [10,11]. Good selection of effective trap is useful not only to reduce the hole refilling effect but also to obtain the high temperature stable hole. The properties of a doubly doped hole burning system are currently under investigation.

Acknowledgements

This work is Excited State Physics, Chinese

4. Conclusion

High temperature hole burning systems $\text{M}_y\text{M}'_{1-y}\text{FCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$ ($\text{M}, \text{M}' = \text{Ca}, \text{Sr}, \text{Ba}$) are prepared. In the system, the inhomogeneous line of Sm^{2+} is broadened greatly with a maximum line width of about 40 cm^{-1} for $y = 0.5$, and room temperature hole burning is performed in $\text{Sr}_{0.5}\text{Ba}_{0.5}\text{FCl}_{0.5}\text{Br}_{0.5}:\text{Sm}^{2+}$. A mixture with the inhomogeneous line width of 65 cm^{-1} is obtained by mixing three samples of the $\text{Sr}_y\text{Ba}_{1-y}$ series for $y = 0, 0.25$ and 0.65 , respectively. Three holes are burnt and probed in the mixture at liquid nitrogen temperature. To overcome hole refilling effect in hole burning process, the introducing of other effective trap different from Sm^{3+} is performed in Sm, Yb doubly doped SrFCl crystals.

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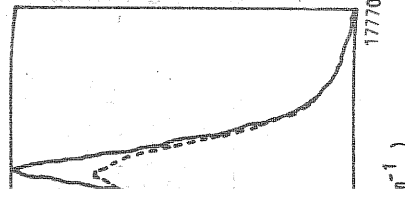


Fig. 4 shows α^{-1} (solid) and after introducing another Sm^{3+} in $\text{SrFCl}:0.5\%$ (dashed). We see that the intensities and the intensities are almost constant after the result is because of the introduction of Sm^{3+} ions under the case of existence of $\text{Cl}:\text{Sm}, \text{Yb}$ is not probably have some or instance, Yb^{3+} ions due to the introduction of traps. Some as $\text{Eu}^{3+}, \text{Tm}^{3+}$, which can act as trap ions in the system. One of the ions in alkaline earth ions by trapping of X-ray or effective trap is the hole refilling effect. The temperature stable hole burning in doubly doped hole burning crystals under investigation.

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